

Features

- Low forward voltage drop
- High reverse voltage
- Hermetic metal cases with ceramic insulators

Typical Applications

- All purpose high power rectifier diodes
- High power resistance welding equipment
- Non-controllable and half-controllable rectifiers
- Controlled rectifiers

$I_{F(AV)}$ **5630 A**
 V_{RRM} **200~1000 V**
 I_{FSM} **58 kA**
 I^2t **16820 10³A²S**



SYMBOL	CHARACTERISTIC	TEST CONDITIONS		T _j (°C)	VALUE			UNIT
					Min	Type	Max	
I _{F(AV)}	Mean forward current	180° half sine wave 50Hz Double side cooled,	T _C =85°C	190			5630	A
V _{RRM}	Repetitive peak reverse voltage	tp=10ms		190	200		1000	V
I _{RRM}	Repetitive peak current	at V _{RRM}		190			100	mA
I _{FSM}	Surge forward current	10ms half sine wave		190			58	kA
I ² t	I ² t for fusing coordination	V _R =0.6V _{RRM}						16820
V _{FO}	Threshold voltage			190			0.63	V
I _F	Forward slope resistance							0.058
V _{FM}	Peak on-state voltage	I _{FM} =5000A, F=32kN		190			0.92	V
Q _{rr}	Recovery charge	I _{FM} =2000A, tp=2000μs, di/dt=-20A/μs, V _R =50V		190		4500		μC
R _{th(j-c)}	Thermal resistance Junction to case	At 180° sine double side cooled Clamping force 32kN					0.013	°C/W
R _{th(c-h)}	Thermal resistance case to heat sink						0.0035	
F _m	Mounting force				27		34	kN
T _{stg}	Stored temperature				-40		190	°C
W _t	Weight					820		g
Outline								

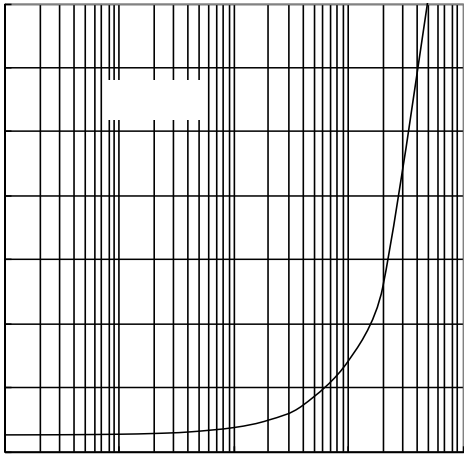


Fig.1

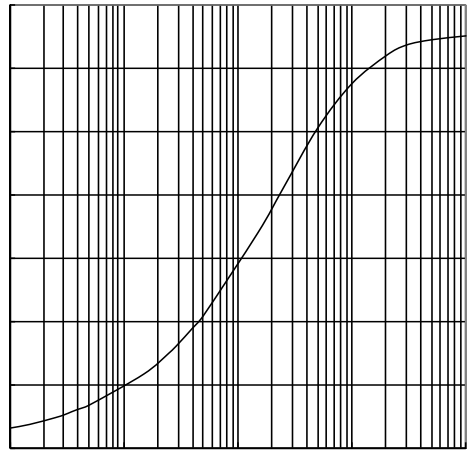


Fig.2

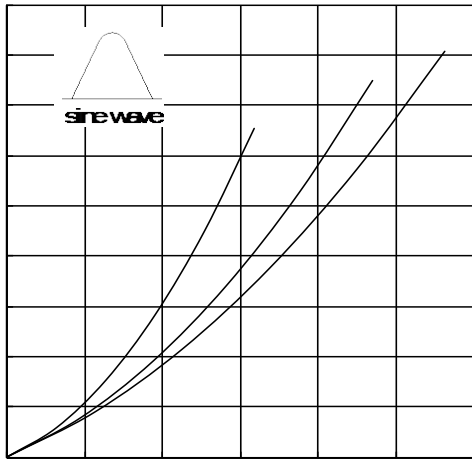


Fig.3

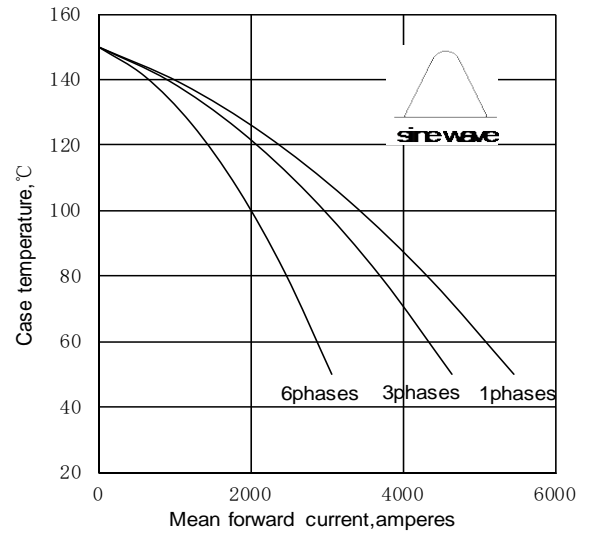


Fig.4

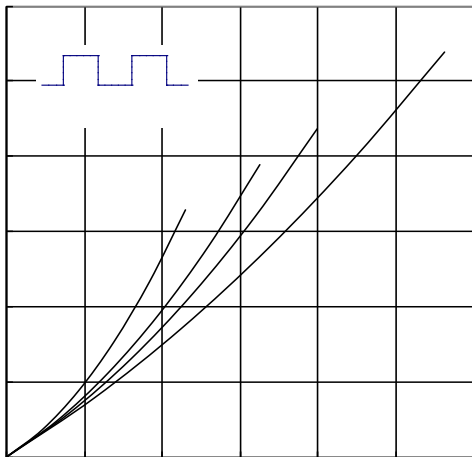


Fig.5

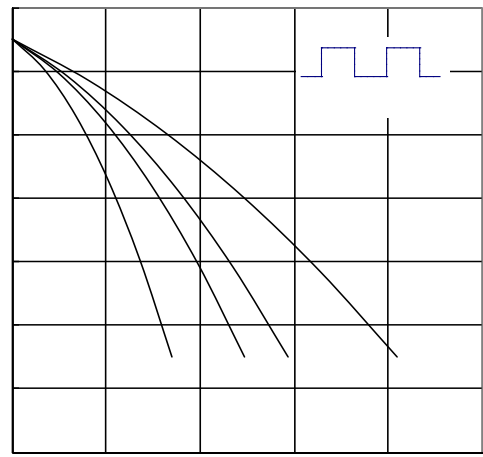


Fig.6

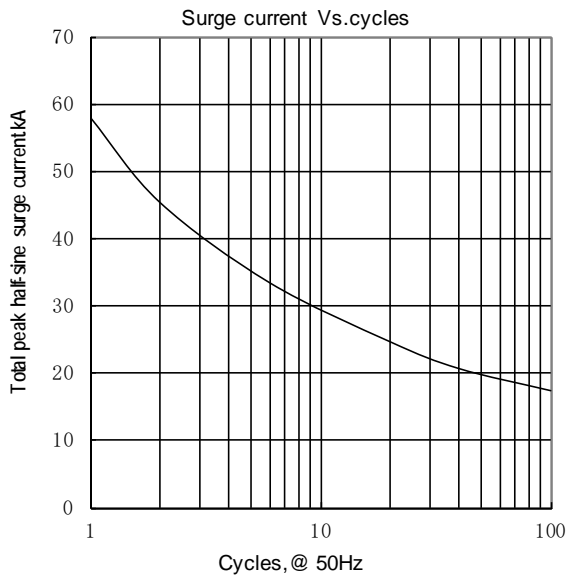


Fig.7

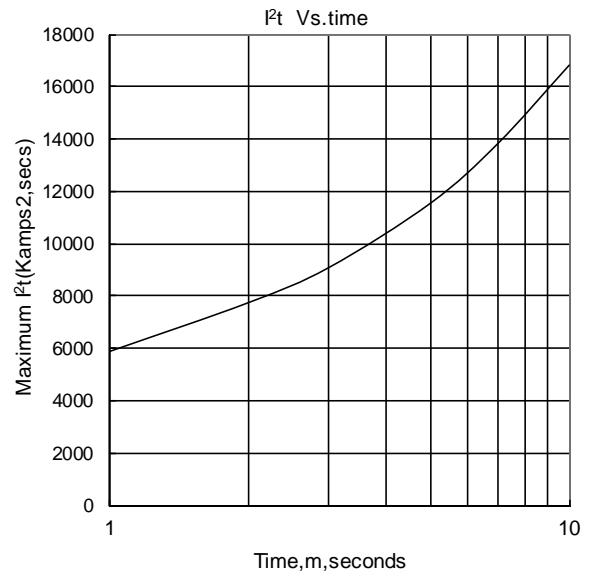


Fig.8

Outline:

